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PATENT
ATTORNEY DOCKET NO.: 46884-5429

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

Seiichi NAGATA

Application No.: 10/551,195

Filed: April 27, 2007

For: SILICON SUBSTRATE AND FORMING
METHOD THEREOF (As Amended)

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Confirmation No.: 4585

Group Art Unit: 2812

Examiner: Unassigned

MAIL STOP PCT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

PRELIMINARY AMENDMENT

Prior to examination on the merits, please amend the above-identified application as follows.